## NSN 5962-01-132-4622

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View Online at https://aerobasegroup.com/nsn/5962-01-132-4622

view Online at https://aerobasegroup.com/hish/0302-01-102-4022
Body Length:
Between 0.740 inches and 0.810 inches
Body Width:
Between 0.280 inches and 0.310 inches
Body Height:
Between 0.110 inches and 0.140 inches
Operating Tempurature Range:
+0.0/+70.0 degrees celsius
Storage Tempurature Range:
65.0/+150.0 degrees celsius
End Application:
Jss/rocc e/i fscm 05869
Features Provided:
Hermetically sealed and monolithic and positive outputs and programmable and w/enable and 3-state output and low power and schottky
nclosure Material:
Ceramic and glass
nclosure Configuration:
Dual-in-line
Output Logic Form:
Transistor-transistor logic
nput Circuit Pattern:
10 input
Terminal Surface Treatment:
Solder
Voltage Rating And Type Per Characteristic:
5.5 volts power source
Time Rating Per Chacteristic:
60.00 nanoseconds propagation delay time, low to high level output and 60.00 nanoseconds propagation delay time, high to low level
putput
Memory Device Type:
Rom
Memory Capacity:
Jnknown
Test Data Document:
33214-472-5016 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.;
excludes any specification, standard or other document that may be referenced in a basic governing drawing)
Terminal Type And Quantity:
16 printed circuit
Shelf Life:
N/a

Yes - demil/mli

**Unit Of Measure:** 

Demilitarization:

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